APPENDIX – I UNIVERSITY OF MUMBAI Syllabus for Certificate Course on SEMICONDUCTOR SCIENCE AND TECHNOLOGY

Paper – I SEMICONDUCTOR SCIENCE.

The Atomic – Bond Model	
Crystal lattices)
Current Carriers	SSD
Doping of semiconductor	>
(SD Chapter - 1)	J
Energy Band Model	
Electron as wave)
Energy Levels in Atom and Energy Bands	SSD
Electron and Hole as Particle	>
Population of electron states	
(SD Chapter – 2)	J
Drift and Diffusion	
Energy bands with applied electric field)
Carrier Mobility	
Diffusion current equation	≻ SSD
Basic continuity equation	
(SD Chapter - 3, 4))
Fundamental Devices Structur	e
P – N Junction Principles	_
DC Mode	
Capacitance in $P - N$ Junction	SAM
BJT Principles	$\left\langle \right\rangle$
Current – Voltage Characteristics	
(SD Chapter – 6))

Metal – Semiconductor Contact and MOSFET Structures

Metal – Semiconductor Contact MOS Capacitor MOSFET Principle and characteristics Nanoscale MOSFETs MOS based Memory Devices (SD Chapter – 7,8)

≻ SAM

Refernce : SD : Principle of Semiconductor Devices – Sima Dimitrijev

Paper II : SEMICONDUCTOR TECHNOLOGY



Power Devices
Power Diodes
Power MOSFET IGBT
Thyristor
(SD Chapter – 14)
DDK

Reference: SD: Principle of Semiconductor Devices – Sima Dimitrijev

Note: The approach can be described as a significant emphasis on explanation by words and figures. Related to mathematical equation, the main role of the word is not to guide the mathematical derivations; it is to explain the meaning and the role of different types of equations.

Practical component will be based on theory learnt. It will include visits to institution with device fabrication facility.
